

CMOS Digital Integrated Circuits Silicon Monolithic

TC7WH126FK

1. Functional Description

• Dual Bus Buffer with 3-State Output

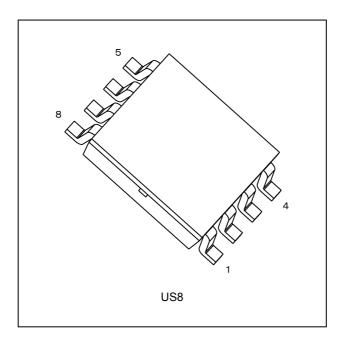
2. Features

- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range: $T_{opr} = -40$ to 125 °C (Note 2)
- (3) High speed operation: $t_{pd} = 3.8 \text{ ns (typ.)}$ ($V_{CC} = 5.0 \text{ V}$, $C_L = 15 \text{ pF}$)
- (4) Low power dissipation: $I_{CC} = 2.0 \mu A \text{ (max) (} T_a = 25 \text{ °C)}$
- (5) High noise immunity: $V_{NIH} = V_{NIL} = 28 \% V_{CC}$ (min)
- (6) 5.5 V tolerant inputs
- (7) Balanced propagation delays: $t_{PLH} \approx t_{PHL}$
- (8) Wide operating voltage range: $V_{CC} = 2.0$ to 5.5 V
- (9) Low noise: $V_{OLP} = 0.8 \text{ V (max)}$

Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

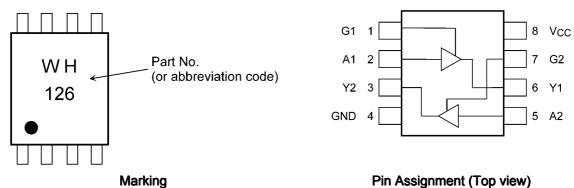
Note 2: For devices with the ordering part number ending in J(CT. T_{opr} = -40 to 85 °C for the other devices.

3. Packaging





4. Marking and Pin Assignment



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5. IEC Logic Symbol



6. Truth Table

| G | А | Y |
|---|---|---|
| L | X | Z |
| Н | L | L |
| Н | Н | Н |

X: Don't care

Z: High impedance

7. Absolute Maximum Ratings (Note) (Unless otherwise specified, T_a = 25 °C)

| Characteristics | Symbol | Note | Rating | Unit |
|---------------------------------|------------------|----------|-------------------------------|------|
| Supply voltage | V _{CC} | | -0.5 to 7.0 | V |
| Input voltage | V_{IN} | | -0.5 to 7.0 | |
| DC output voltage | V_{OUT} | | -0.5 to V _{CC} + 0.5 | |
| Input diode current | I _{IK} | | -20 | mA |
| Output diode current | l _{ok} | (Note 1) | ±20 | |
| DC output current | l _{out} | | ±25 | |
| V _{CC} /ground current | I _{CC} | | ±50 | |
| Power dissipation | P _D | | 200 | mW |
| Storage temperature | T _{stg} | | -65 to 150 | °C |

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: $V_{OUT} < GND$, $V_{OUT} > V_{CC}$



8. Operating Ranges (Note)

| Characteristics | Symbol | Note | Test Condition | Rating | Unit |
|--------------------------|------------------|----------|-------------------------------|----------------------|------|
| Supply voltage | V _{CC} | | _ | 2.0 to 5.5 | V |
| Input voltage | V _{IN} | | _ | 0 to 5.5 | |
| Output voltage | V _{OUT} | | _ | 0 to V _{CC} | |
| Operating temperature | T _{opr} | (Note 1) | _ | -40 to 125 | °C |
| | | (Note 2) | _ | -40 to 85 | |
| Input rise and fall time | dt/dv | | V_{CC} = 3.3 ± 0.3 V | 0 to 100 | ns/V |
| | | | V _{CC} = 5.0 ± 0.5 V | 0 to 20 | |

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either V_{CC} or GND.

Note 1: For devices with the ordering part number ending in J(CT.

Note 2: For devices except those with the ordering part number ending in J(CT.

9. Electrical Characteristics

9.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

| Characteristics | Symbol | Test Condition | | V _{CC} (V) | Min | Тур. | Max | Unit |
|--|-----------------|---|--------------------------|---------------------|-----------------------|------|---------------------|------|
| High-level input voltage | V _{IH} | _ | | 2.0 | 1.5 | _ | _ | V |
| | | | | 3.0 to 5.5 | V _{CC} × 0.7 | _ | _ | |
| Low-level input voltage | V _{IL} | _ | | 2.0 | _ | _ | 0.5 | V |
| | | | | 3.0 to 5.5 | _ | _ | $V_{CC} \times 0.3$ | |
| High-level output voltage | V _{OH} | V _{IN} = V _{IH} | I _{OH} = -50 μA | 2.0 | 1.9 | 2.0 | _ | ٧ |
| | | | | 3.0 | 2.9 | 3.0 | _ | |
| | | | | 4.5 | 4.4 | 4.5 | _ | |
| | | | I_{OH} = -4 mA | 3.0 | 2.58 | | _ | |
| | | | I_{OH} = -8 mA | 4.5 | 3.94 | | _ | |
| Low-level output voltage | V _{OL} | $V_{IN} = V_{IH}$ or V_{IL} | I_{OL} = 50 μ A | 2.0 | _ | 0.0 | 0.1 | V |
| | | | | 3.0 | _ | 0.0 | 0.1 | |
| | | | | 4.5 | _ | 0.0 | 0.1 | |
| | | | I_{OL} = 4 mA | 3.0 | _ | _ | 0.36 | |
| | | | I_{OL} = 8 mA | 4.5 | _ | | 0.36 | |
| 3-state output OFF-state leakage current | l _{oz} | $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$ | | 5.5 | _ | | ±0.25 | μА |
| Input leakage current | I _{IN} | V _{IN} = 5.5 V or GND | | 0 to 5.5 | _ | _ | ±0.1 | μА |
| Quiescent supply current | Icc | $V_{IN} = V_{CC}$ or GND | | 5.5 | _ | _ | 2.0 | μА |



9.2. DC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

| Characteristics | Symbol | Test Conditio | V _{CC} (V) | Min | Max | Unit | |
|--|-----------------|---|--------------------------|------------|---------------------|---------------------|----|
| High-level input voltage | V _{IH} | _ | | 2.0 | 1.5 | _ | V |
| | | | | 3.0 to 5.5 | $V_{CC} \times 0.7$ | _ | |
| Low-level input voltage | V _{IL} | _ | | 2.0 | _ | 0.5 | V |
| | | | | 3.0 to 5.5 | _ | $V_{CC} \times 0.3$ | |
| High-level output voltage | V _{OH} | V _{IN} = V _{IH} | I _{OH} = -50 μA | 2.0 | 1.9 | _ | ٧ |
| | | | | 3.0 | 2.9 | _ | |
| | | | | 4.5 | 4.4 | _ | |
| | | | I_{OH} = -4 mA | 3.0 | 2.48 | _ | |
| | | | I_{OH} = -8 mA | 4.5 | 3.80 | _ | |
| Low-level output voltage | V _{OL} | V _{IN} = V _{IH} or V _{IL} | I _{OL} = 50 μA | 2.0 | _ | 0.1 | ٧ |
| | | | | 3.0 | _ | 0.1 | |
| | | | | 4.5 | _ | 0.1 | |
| | | | I_{OL} = 4 mA | 3.0 | _ | 0.44 | |
| | | | I_{OL} = 8 mA | 4.5 | _ | 0.44 | |
| 3-state output OFF-state leakage current | I _{OZ} | $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$ | | 5.5 | _ | ±2.5 | μА |
| Input leakage current | I _{IN} | V _{IN} = 5.5 V or GND | | 0 to 5.5 | _ | ±1.0 | μΑ |
| Quiescent supply current | Icc | V _{IN} = V _{CC} or GND | | 5.5 | _ | 20.0 | μА |

9.3. DC Characteristics (Note) (Unless otherwise specified, T_a = -40 to 125 °C)

| Characteristics | Symbol | Test Conditio | n | V _{CC} (V) | Min | Max | Unit |
|--|-----------------|---|--------------------------|---------------------|---------------------|---------------------|------|
| High-level input voltage | V _{IH} | _ | | 2.0 | 1.5 | _ | V |
| | | | | 3.0 to 5.5 | $V_{CC} \times 0.7$ | _ | |
| Low-level input voltage | V _{IL} | _ | | 2.0 | _ | 0.5 | V |
| | | | | 3.0 to 5.5 | _ | $V_{CC} \times 0.3$ | |
| High-level output voltage | V _{OH} | $V_{IN} = V_{IH}$ | I _{OH} = -50 μA | 2.0 | 1.9 | _ | V |
| | | | | 3.0 | 2.9 | _ | |
| | | | | 4.5 | 4.4 | _ | |
| | | | I_{OH} = -4 mA | 3.0 | 2.40 | _ | |
| | | | I_{OH} = -8 mA | 4.5 | 3.70 | _ | |
| Low-level output voltage | V _{OL} | V _{IN} = V _{IH} or V _{IL} | I _{OL} = 50 μA | 2.0 | _ | 0.1 | V |
| | | | | 3.0 | _ | 0.1 | |
| | | | | 4.5 | _ | 0.1 | |
| | | | I _{OL} = 4 mA | 3.0 | _ | 0.55 | |
| | | | I _{OL} = 8 mA | 4.5 | _ | 0.55 | |
| 3-state output OFF-state leakage current | l _{OZ} | $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$ | | 5.5 | _ | ±10.0 | μА |
| Input leakage current | I _{IN} | V _{IN} = 5.5 V or GND | | 0 to 5.5 | | ±2.0 | μΑ |
| Quiescent supply current | I _{CC} | V _{IN} = V _{CC} or GND | | 5.5 | _ | 40.0 | μΑ |

Note: For devices with the ordering part number ending in J(CT.



9.4. AC Characteristics (Unless otherwise specified, T_a = 25 °C, Input: t_r = t_f = 3 ns)

| Characteristics | Symbol | Note | Test Condition | V _{CC} (V) | C _L (pF) | Min | Тур. | Max | Unit |
|-------------------------------|--------------------------------------|----------|-------------------|---------------------|---------------------|-----|------|------|------|
| Propagation delay time | t _{PLH} ,t _{PHL} | | _ | 3.3 ± 0.3 | 15 | _ | 5.6 | 8.0 | ns |
| | | | | | 50 | | 8.1 | 11.5 | |
| | | | | 5.0 ± 0.5 | 15 | | 3.8 | 5.5 | |
| | | | | | 50 | | 5.3 | 7.5 | |
| 3-state output enable time | t _{PZL} ,t _{PZH} | | $R_L = 1 k\Omega$ | 3.3 ± 0.3 | 15 | | 5.4 | 8.0 | ns |
| | | | | | 50 | | 7.9 | 11.5 | |
| | | | | 5.0 ± 0.5 | 15 | | 3.6 | 5.1 | |
| | | | | | 50 | _ | 5.1 | 7.1 | |
| 3-state output disable time | t_{PLZ}, t_{PHZ} | | $R_L = 1 k\Omega$ | 3.3 ± 0.3 | 50 | | 9.5 | 13.2 | ns |
| | | | | 5.0 ± 0.5 | 50 | | 6.1 | 8.8 | |
| Output skew | t _{osLH} ,t _{osHL} | (Note 1) | | 3.3 ± 0.3 | 50 | | | 1.5 | ns |
| | | | | 5.0 ± 0.5 | 50 | _ | _ | 1.0 | |
| Input capacitance | C _{IN} | | ı | | | | 4 | 10 | pF |
| Output capacitance | C _{OUT} | | | | | _ | 6 | _ | pF |
| Power dissipation capacitance | C _{PD} | (Note 2) | _ | | | _ | 15 | _ | pF |

Note 1: Parameter guaranteed by design. $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation. $I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2 \text{ (per 1 bit)}$

9.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

| Characteristics | Symbol | Note | Test Condition | V _{CC} (V) | C _L (pF) | Min | Max | Unit |
|-----------------------------|--------------------------------------|----------|-------------------|---------------------|---------------------|-----|------|------|
| Propagation delay time | t _{PLH} ,t _{PHL} | | _ | 3.3 ± 0.3 | 15 | 1.0 | 9.5 | ns |
| | | | | | 50 | 1.0 | 13.0 | |
| | | | | 5.0 ± 0.5 | 15 | 1.0 | 6.5 | |
| | | | | | 50 | 1.0 | 8.5 | |
| 3-state output enable time | t _{PZL} ,t _{PZH} | | $R_L = 1 k\Omega$ | 3.3 ± 0.3 | 15 | 1.0 | 9.5 | ns |
| | | | | | 50 | 1.0 | 13.0 | |
| | | | | 5.0 ± 0.5 | 15 | 1.0 | 6.0 | |
| | | | | | 50 | 1.0 | 8.0 | |
| 3-state output disable time | t _{PLZ} ,t _{PHZ} | | $R_L = 1 k\Omega$ | 3.3 ± 0.3 | 50 | 1.0 | 15.0 | ns |
| | | | | 5.0 ± 0.5 | 50 | 1.0 | 10.0 | |
| Output skew | t _{osLH} ,t _{osHL} | (Note 1) | _ | 3.3 ± 0.3 | 50 | _ | 1.5 | ns |
| | | | | 5.0 ± 0.5 | 50 | _ | 1.0 | |
| Input capacitance | C _{IN} | | _ | | | _ | 10 | pF |

Note 1: Parameter guaranteed by design. $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$



9.6. AC Characteristics (Note) (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

| Characteristics | Symbol | Note | Test Condition | V _{CC} (V) | C _L (pF) | Min | Max | Unit |
|-----------------------------|--------------------------------------|----------|-------------------|---------------------|---------------------|-----|------|------|
| Propagation delay time | t _{PLH} ,t _{PHL} | | _ | 3.3 ± 0.3 | 15 | 1.0 | 11.0 | ns |
| | | | | | 50 | 1.0 | 14.5 | |
| | | | | 5.0 ± 0.5 | 15 | 1.0 | 7.5 | |
| | | | | | 50 | 1.0 | 9.5 | |
| 3-state output enable time | t _{PZL} ,t _{PZH} | | $R_L = 1 k\Omega$ | 3.3 ± 0.3 | 15 | 1.0 | 11.0 | ns |
| | | | | | 50 | 1.0 | 14.5 | |
| | | | | 5.0 ± 0.5 | 15 | 1.0 | 7.0 | |
| | | | | | 50 | 1.0 | 9.0 | |
| 3-state output disable time | t_{PLZ}, t_{PHZ} | | $R_L = 1 k\Omega$ | 3.3 ± 0.3 | 50 | 1.0 | 16.5 | ns |
| | | | | 5.0 ± 0.5 | 50 | 1.0 | 11.0 | |
| Output skew | t _{osLH} ,t _{osHL} | (Note 1) | _ | 3.3 ± 0.3 | 50 | _ | 1.5 | ns |
| | | | | 5.0 ± 0.5 | 50 | _ | 1.0 | |
| Input capacitance | C _{IN} | | _ | | | _ | 10 | pF |

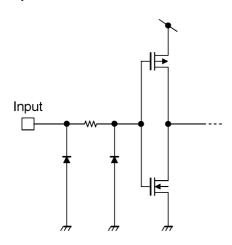
Note: For devices with the ordering part number ending in J(CT.

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m - t_{PLH}n|$, $t_{osHL} = |t_{PHL}m - t_{PHL}n|$)

9.7. Noise Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_f = t_f = 3$ ns)

| Characteristics | Symbol | Test Condition | V _{CC} (V) | Тур. | Limit | Unit |
|--|------------------|------------------------|---------------------|------|-------|------|
| Quiet output maximum dynamic V _{OL} | V _{OLP} | C _L = 50 pF | 5.0 | 0.3 | 0.8 | V |
| Quiet output minimum dynamic V _{OL} | V _{OLV} | C _L = 50 pF | 5.0 | -0.3 | -0.8 | V |
| Minimum high-level dynamic input voltage | V_{IHD} | C _L = 50 pF | 5.0 | | 3.5 | V |
| Maximum low-level dynamic input voltage | V_{ILD} | C _L = 50 pF | 5.0 | | 1.5 | V |

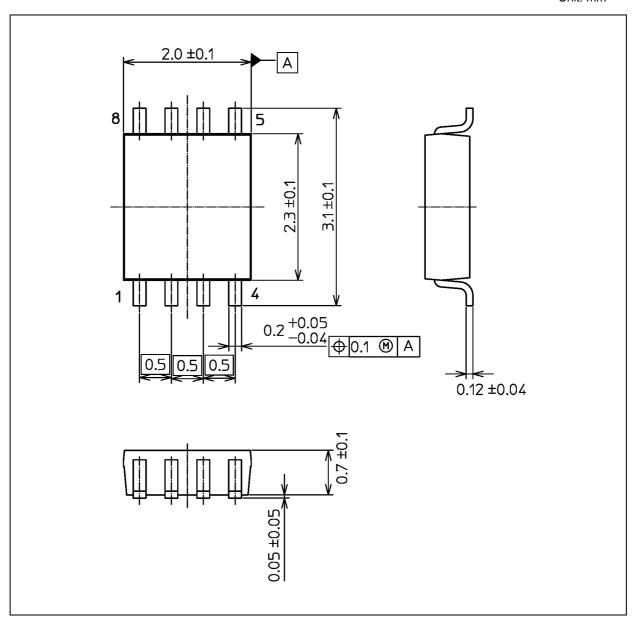
10. Input Equivalent Circuit





Package Dimensions

Unit: mm



Weight: 0.01 g (typ.)

| Package Name(s) |
|-----------------|
| JEDEC: SOT-765 |
| Nickname: US8 |



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